

# Pump and Probe experiments from first-principles in bulk silicon: ultra-fast carrier relaxation and transient reflectivity

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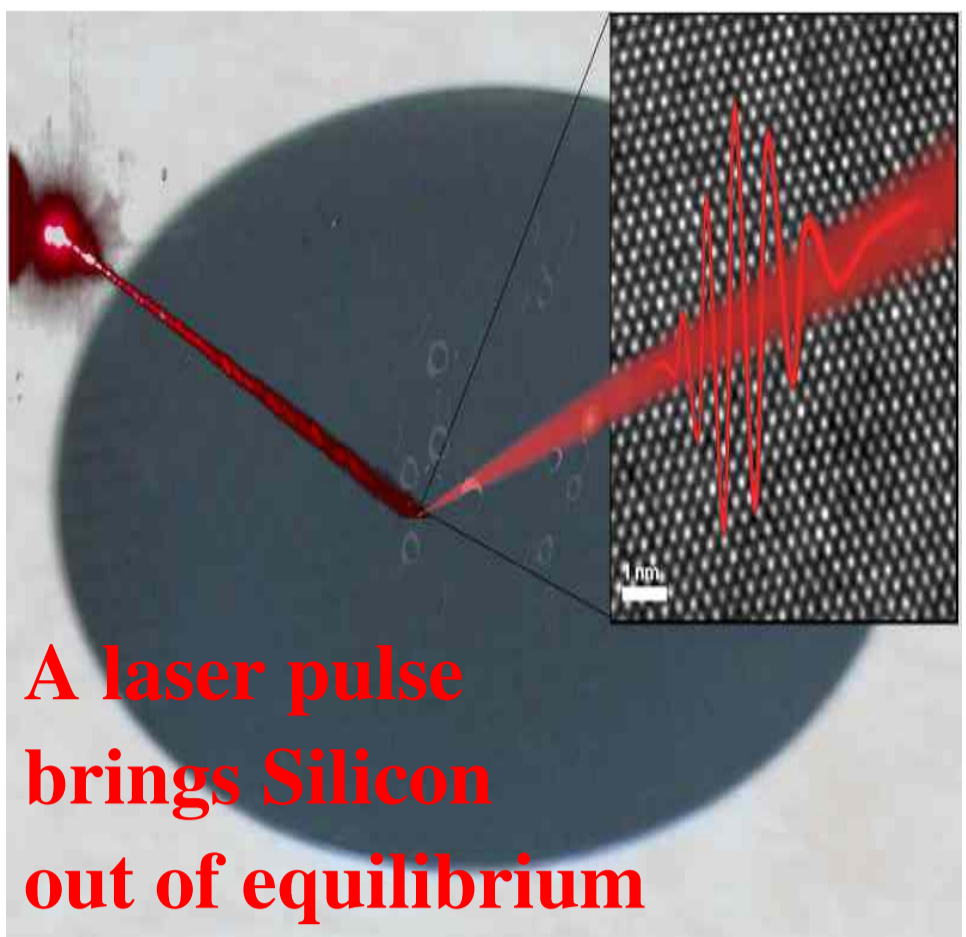
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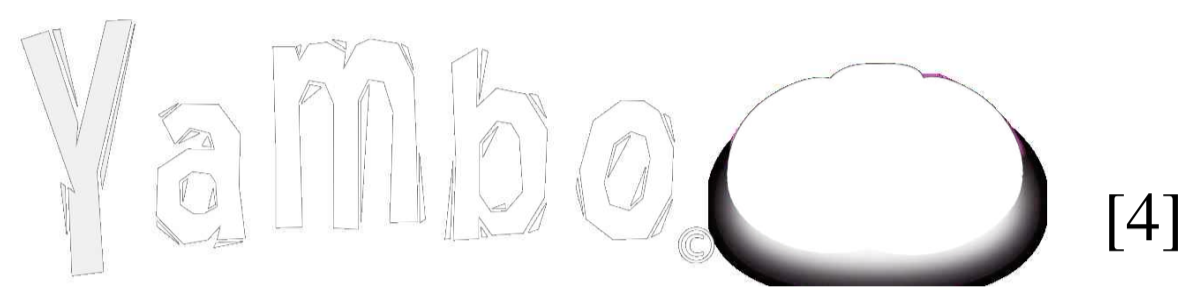
## Abstract

The development of ultra-short laser pulses has opened the opportunity to investigate the dynamics of electrons on the fs time-scale ( $10^{-15}$  s). After the photo-excitation with such laser pulses, electrons are in a regime which is highly out-of-equilibrium. Here we present a novel numerical approach, based on the merging of the out-of-equilibrium Green's function method with Density-Functional-Theory, to describe this regime in semiconductors. Silicon is used as reference material to show the physical process involved. The simulations are also compared with recent two photon photo-emission and transient-reflectivity measurements. In the 2PPE experiment we show that different processes take place: (i) scattering between degenerate states, activated by the pump-pulse induced symmetry breaking, (ii) L  $\rightarrow$  X inter-valley scattering, and, finally, (iii) the relaxation towards the thermal equilibrium. In the TR experiment we underline the key role of optical-gap renormalization induced by the pump pulse, combined with bleaching, needed to explain the experimental signal. Moreover we discuss how the same approach is able to capture coherent excitons in materials with strong electron-hole interaction. This ensures a correct description of the interaction with the pump pulse. Finally we consider a model system with strong electron-hole interaction and discuss how the approach should be extended to capture the formation of non-coherent exciton populations and describe time resolved photoemission in this case.



A laser pulse brings Silicon out of equilibrium

## Non-equilibrium Green functions [1-3] Fully ab-initio approach:



$$i\partial_t G^< - [H^0 + V^H + U^{ext} + \Sigma_s, G^<] = \{\Sigma^>, G^<\} - \{\Sigma^<, G^>\}$$

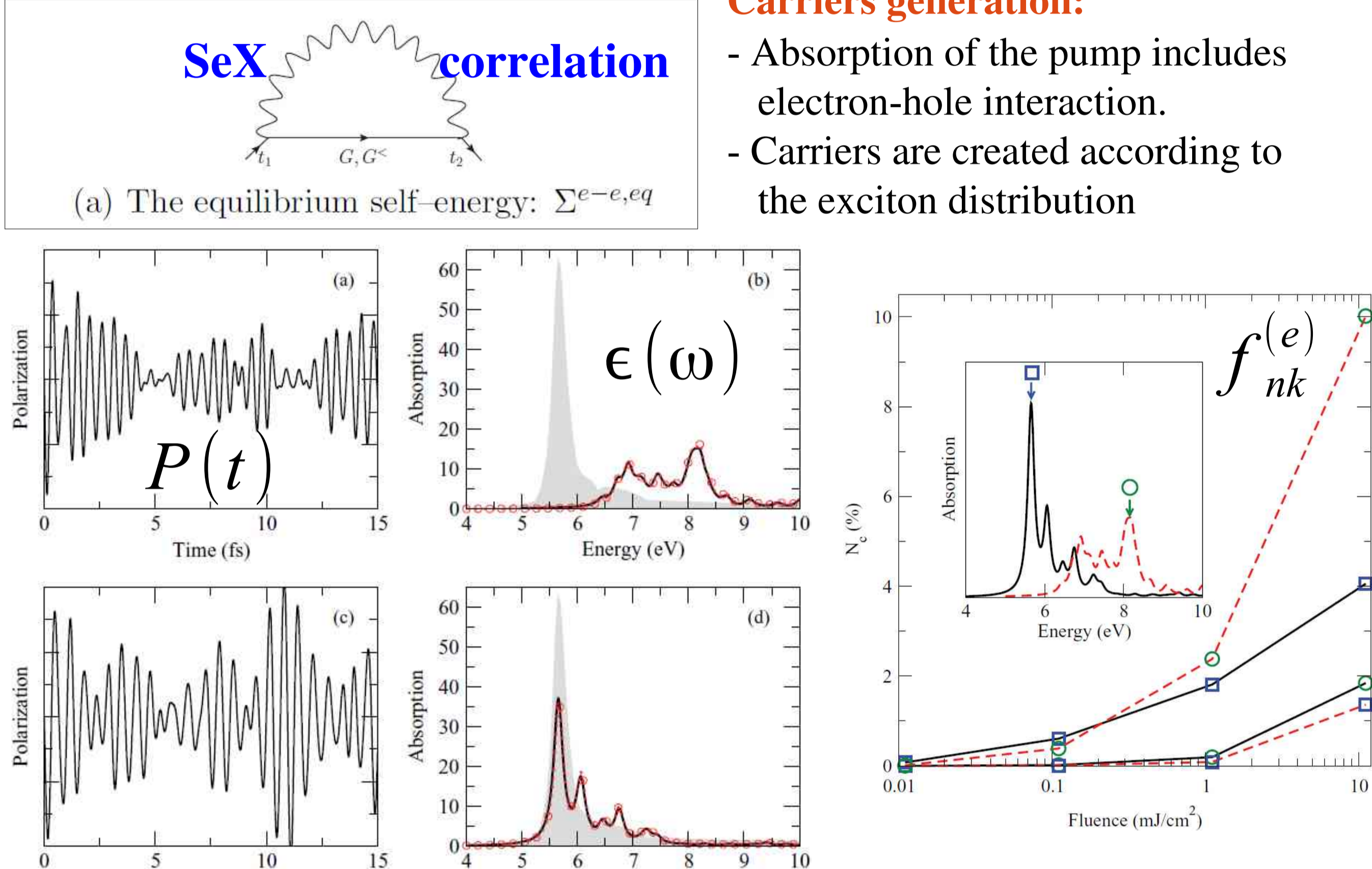
$$f_{nk}^{(elh)}(t) \approx \mp i \Delta G_{nmk}^<(t) \quad P(t) = -e \sum_{nmk} r_{nmk} \Delta G_{nmk}^<(t)$$

microscopic version of the optical Maxwell-Bloch equations for  $f(t)$  and  $P(t)$

## Coherent excitons: absorption of the pump-pulse [1]

### Carriers generation:

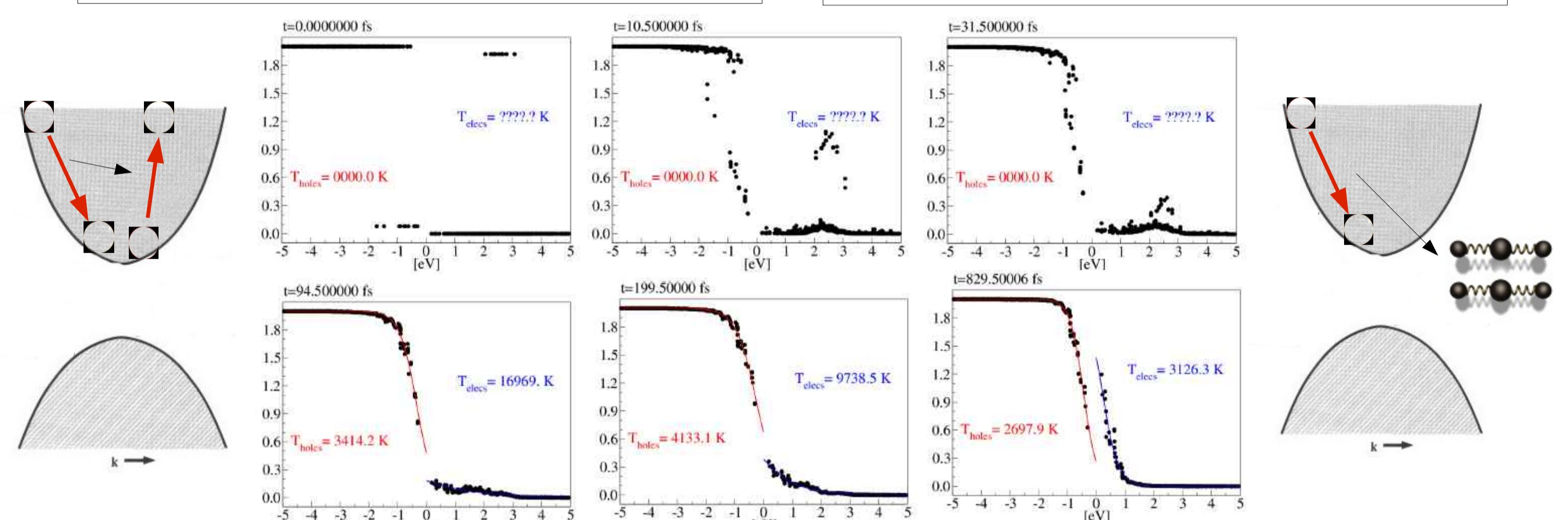
- Absorption of the pump includes electron-hole interaction.
- Carriers are created according to the exciton distribution



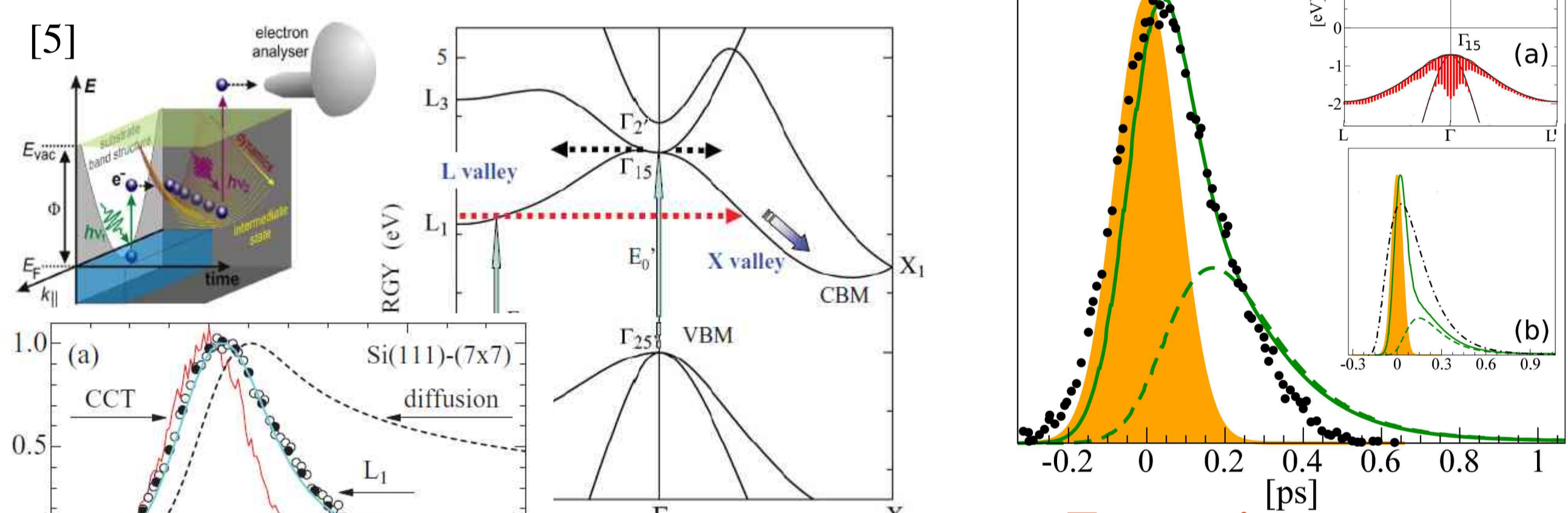
## Carrier dynamics: scattering processes [2-3]

(b) The out-of-equilibrium self-energy:  $\Sigma^{e-e}$   
non-eq. GW: el-el scattering

(c) The Fan self-energy:  $\Sigma^{e-p}$   
Fan  $\Sigma$ : el-ph scattering

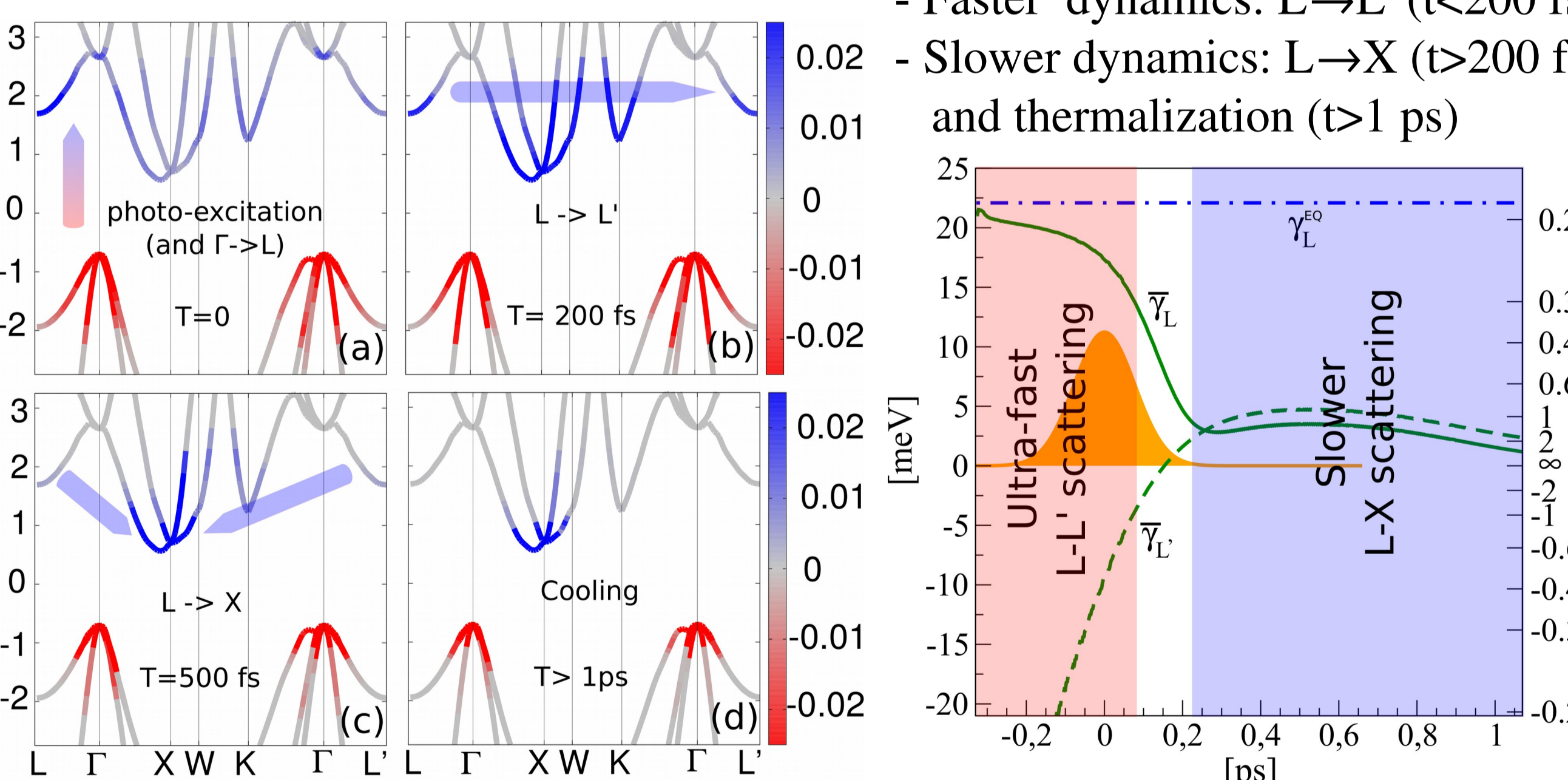


## Two photons photo-emission: [6]

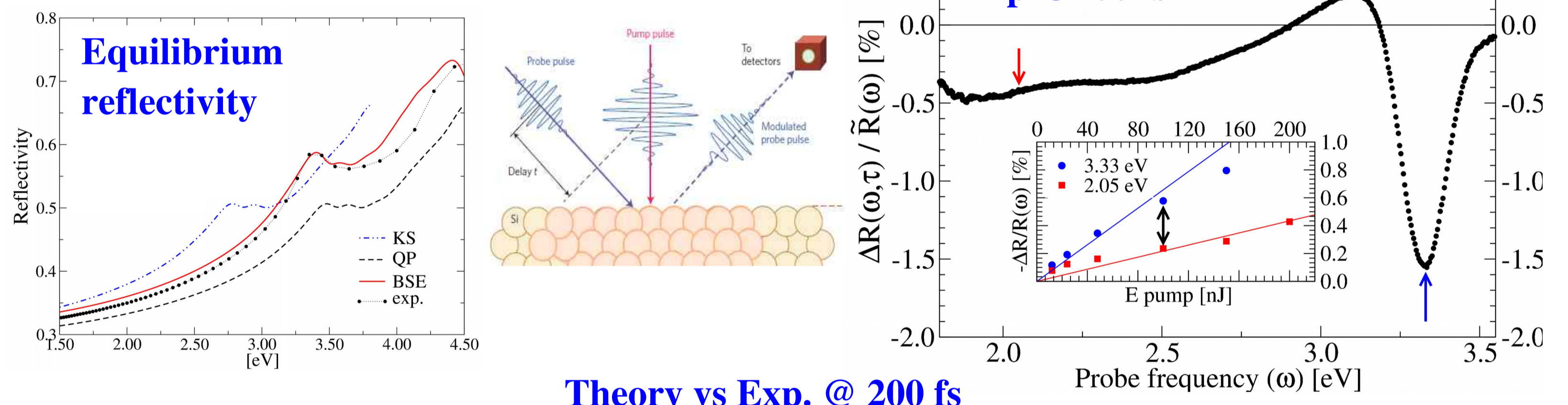


### Two regimes:

- Faster dynamics: L  $\rightarrow$  L' ( $t < 200$  fs)
- Slower dynamics: L  $\rightarrow$  X ( $t > 200$  fs) and thermalization ( $t > 1$  ps)

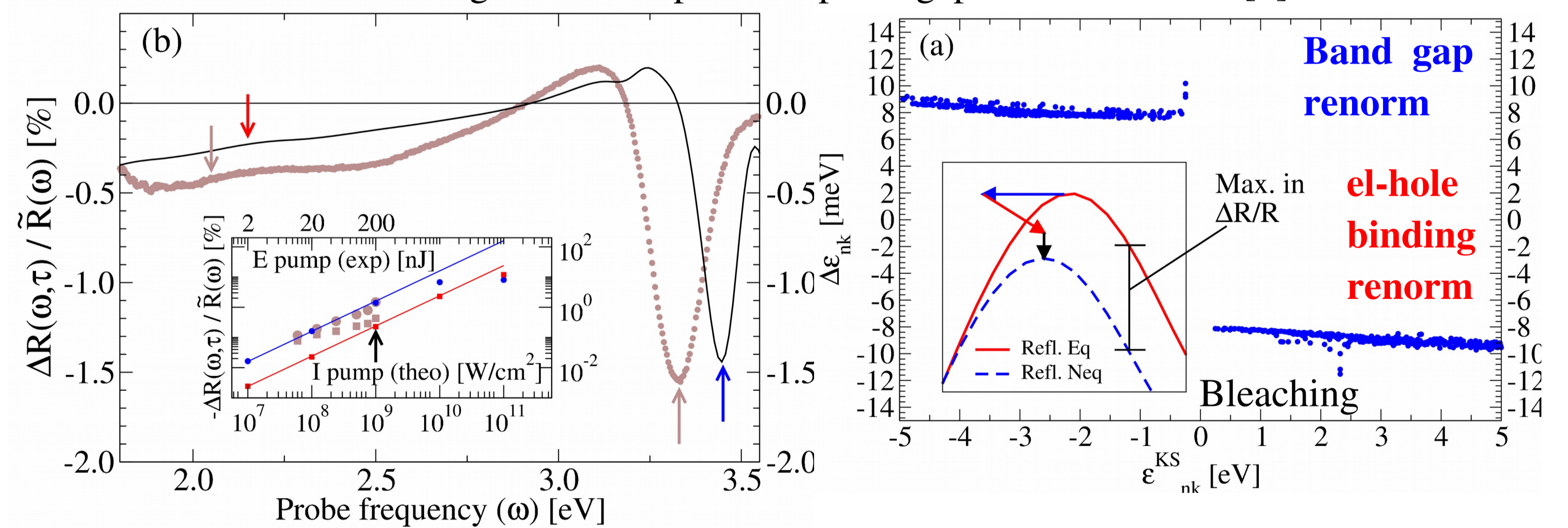


## Transient reflectivity [7-8]



### Theory vs Exp. @ 200 fs

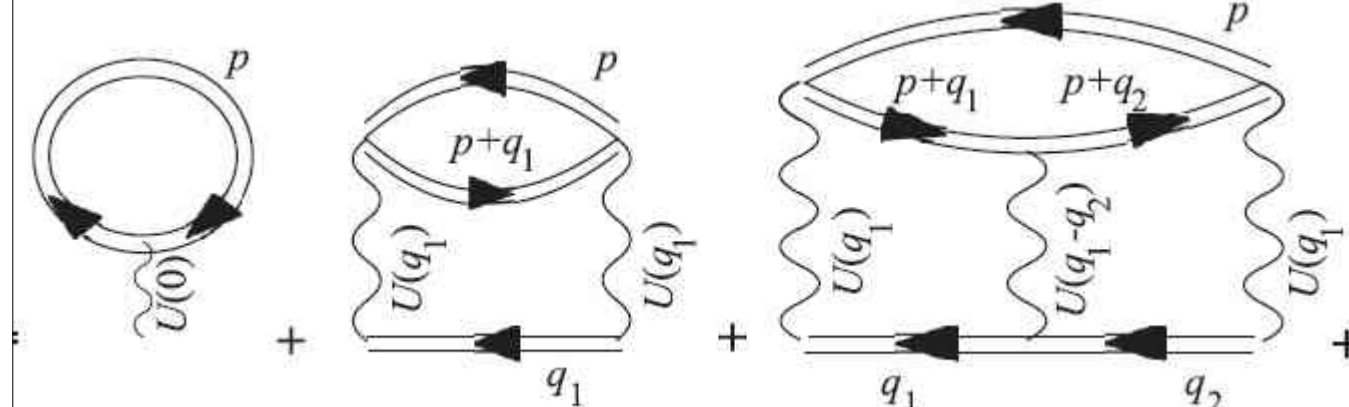
### Bleaching of the first peak + Optical gap renormalization [8]



## Non coherent excitons population [9]

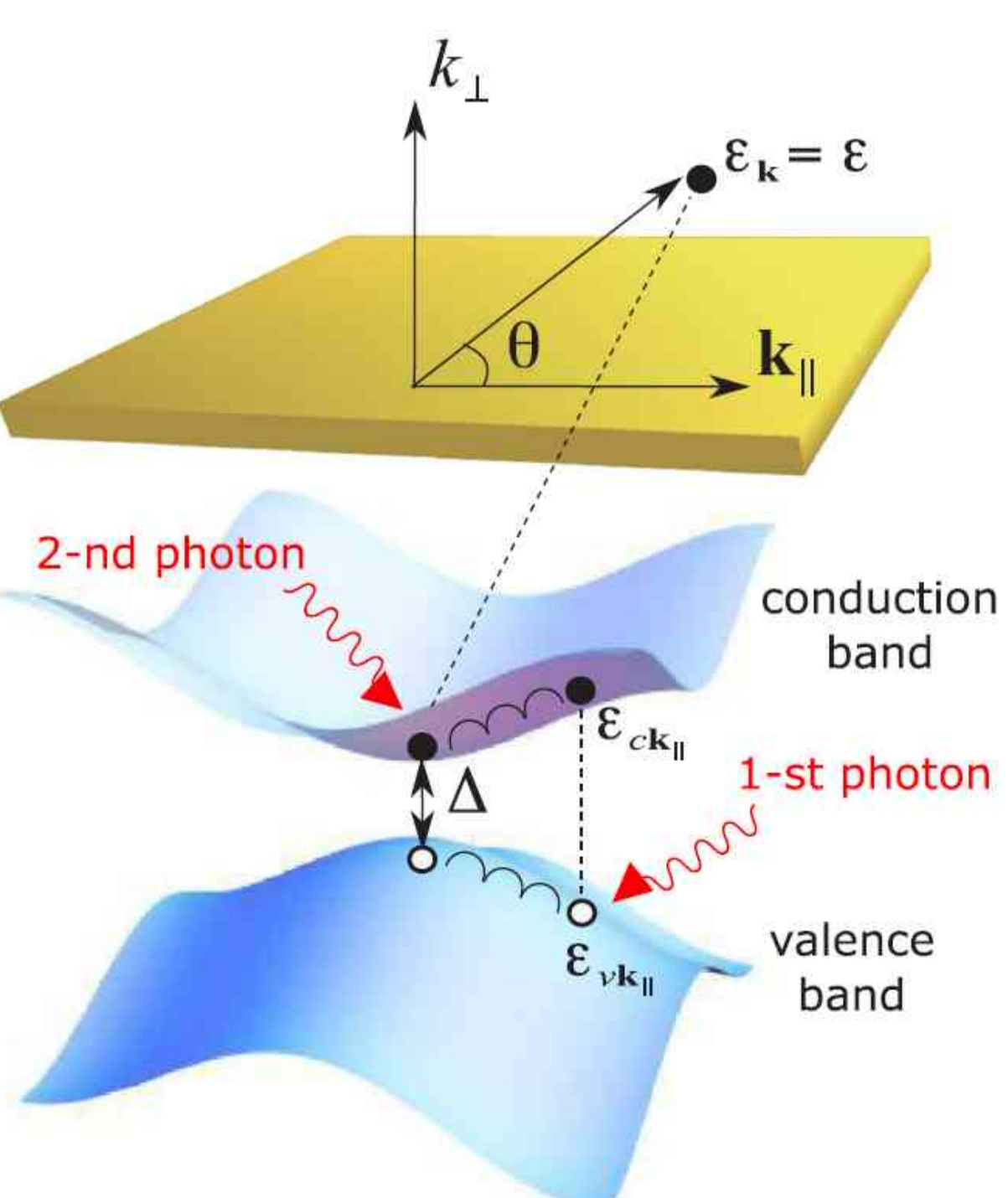
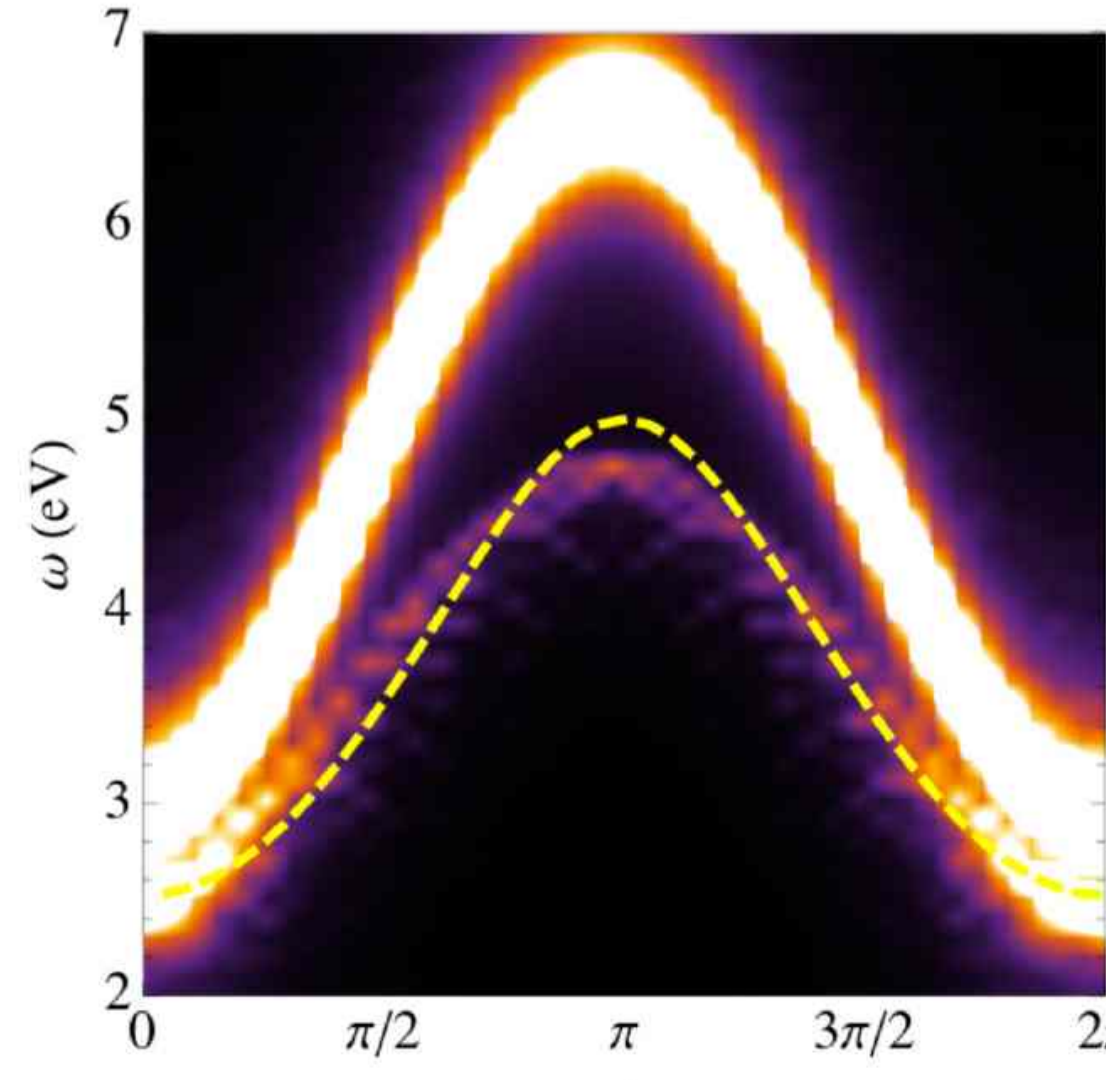
- non coherent excitons require higher order correlation
- in alternative they could be describe

### T-matrix correlation



$$I(k) = -i|a_0 D_k|^2 [G_{cc,k_1}^<(\epsilon_{fk} - \omega_0) + G_{cc,k_1}^<(\epsilon_{fk} + \omega_0)]$$

### Exciton in TR-ARPES



## References & Acknowledgments

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